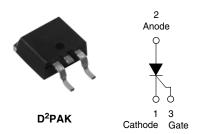




Vishay High Power Products

# **Surface Mountable Phase Control SCR, 10 A**



PRODUCT SUMMARY					
V <sub>T</sub> at 6.5 A	< 1.15 V				
I <sub>TSM</sub>	140 A				
$V_{RRM}$	800 V				

#### **DESCRIPTION/FEATURES**

The 10TTS08SPbF High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.





COMPLIANT

HALOGEN

**FREE** 

Typical applications are in input rectification (soft start) and these products are designed to be used with Vishay HPP input diodes, switches

used with Vishay HPP input diodes, switches and output rectifiers which are available in identical p

and output rectifiers which are available in identical package outlines.

This product has been designed and qualified for industrial level.

Compliant to RoHS directive 2002/95/EC.

Halogen-free according to IEC 61249-2-21 definition.

OUTPUT CURRENT IN TYPICAL APPLICATIONS							
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS				
NEMA FR-4 or G-10 glass fabric-based epoxy with 4 oz. (140 μm) copper	2.5	3.5					
Aluminum IMS, $R_{thCA} = 15  ^{\circ}C/W$	6.3	9.5	A				
Aluminum IMS with heatsink, R <sub>thCA</sub> = 5 °C/W	14.0	18.5					

#### Note

•  $T_A = 55$  °C,  $T_J = 125$  °C, footprint 300 mm<sup>2</sup>

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
I <sub>T(AV)</sub>	Sinusoidal waveform	6.5	A		
I <sub>RMS</sub>		10	A		
V <sub>RRM</sub> /V <sub>DRM</sub>		800	V		
I <sub>TSM</sub>		140	Α		
V <sub>T</sub>	6.5 A, T <sub>J</sub> = 25 °C	1.15	V		
dV/dt		150	V/μs		
dl/dt		100	A/μs		
TJ	Range	- 40 to 125	°C		

VOLTAGE RATINGS						
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>DRM</sub> , MAXIMUM PEAK DIRECT VOLTAGE V	I <sub>RRM</sub> /I <sub>DRM</sub> AT 125 °C mA			
10TTS08SPbF	800	800	1.0			

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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average on-state current	I <sub>T(AV)</sub>	T <sub>C</sub> = 112 °C, 180° conduction half sine wave		6.5	
Maximum RMS on-state current	I <sub>T(RMS)</sub>	1C = 112 C, 160 CONGU	Clion riali sirie wave	10	Α
Maximum peak, one-cycle,	ı	10 ms sine pulse, rated V	/ <sub>RRM</sub> applied, T <sub>J</sub> = 125 °C	120	A
non-repetitive surge current	I <sub>TSM</sub>	10 ms sine pulse, no volt	age reapplied, T <sub>J</sub> = 125 °C	140	
Maximum 12+ for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V	/ <sub>RRM</sub> applied, T <sub>J</sub> = 125 °C	72	A <sup>2</sup> s
Maximum I <sup>2</sup> t for fusing		10 ms sine pulse, no volt	10 ms sine pulse, no voltage reapplied, T <sub>J</sub> = 125 °C		
Maximum I <sup>2</sup> √t for fusing	I²√t	$t = 0.1$ ms to 10 ms, no voltage reapplied, $T_J = 125$ °C		1000	A²√s
Maximum on-state voltage drop	$V_{TM}$	6.5 A, T <sub>J</sub> = 25 °C		1.15	٧
On-state slope resistance	r <sub>t</sub>	T 405 00		17.3	mΩ
Threshold voltage	V <sub>T(TO)</sub>	T <sub>J</sub> = 125 °C	0.85	V	
Maximum varyage and divest leakage accurant		T <sub>J</sub> = 25 °C	V Dated V A	0.05	
Maximum reverse and direct leakage current	I <sub>RM</sub> /I <sub>DM</sub>	T <sub>J</sub> = 125 °C	V <sub>R</sub> = Rated V <sub>RRM</sub> /V <sub>DRM</sub>	1.0	mA
Typical holding current	I <sub>H</sub>	Anode supply = 6 V, resistive load, initial $I_T = 1 A$		30	mA
Maximum latching current	ΙL	Anode supply = 6 V, resistive load		50	
Maximum rate of rise of off-state voltage	dV/dt	T <sub>J</sub> = 25 °C		150	V/µs
Maximum rate of rise of turned-on current	dl/dt	100		100	A/μs

TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	$P_{GM}$		8.0	W
Maximum average gate power	$P_{G(AV)}$		2.0	VV
Maximum peak positive gate current	+I <sub>GM</sub>		1.5	Α
Maximum peak negative gate voltage	-V <sub>GM</sub>		10	٧
	I <sub>GT</sub>	Anode supply = 6 V, resistive load, $T_J = -65 ^{\circ}\text{C}$	20	
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, $T_J = 25$ °C	15	mA
		Anode supply = 6 V, resistive load, T <sub>J</sub> = 125 °C	10	
		Anode supply = 6 V, resistive load, T <sub>J</sub> = - 65 °C	1.2	
Maximum required DC gate voltage to trigger	V <sub>GT</sub>	Anode supply = 6 V, resistive load, $T_J = 25$ °C	1	V
vollage to ingger		Anode supply = 6 V, resistive load, T <sub>J</sub> = 125 °C	0.7	V
Maximum DC gate voltage not to trigger	$V_{GD}$	$T_J = 125 ^{\circ}\text{C},  V_{DRM} = \text{Rated value}$ 0.2 0.1		
Maximum DC gate current not to trigger	I <sub>GD</sub>			mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t <sub>gt</sub>	T <sub>J</sub> = 25 °C	0.8	
Typical reverse recovery time	t <sub>rr</sub>	T 105 90	3	μs
Typical turn-off time	tq	T <sub>J</sub> = 125 °C		

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For technical questions, contact: diodestech@vishay.com



Surface Mountable Vishay High Power Products Phase Control SCR, 10 A

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 40 to 125	°C
Soldering temperature	T <sub>S</sub>	For 10 s (1.6 mm from case)	240	
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	1.5	°C/W
Typical thermal resistance, junction to ambient (PCB mount)	R <sub>thJA</sub> <sup>(1)</sup>		40	C/VV
Approximate weight			2	g
Approximate weight			0.07	oz.
Marking device		Case style D <sup>2</sup> PAK (SMD-220)	10TTS	08S

#### Note

 $<sup>^{(1)}</sup>$  When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140  $\mu m$ ) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

### Vishay High Power Products

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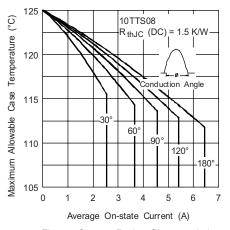


Fig. 1 - Current Rating Characteristics

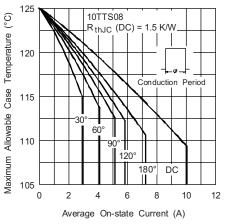


Fig. 2 - Current Rating Characteristics

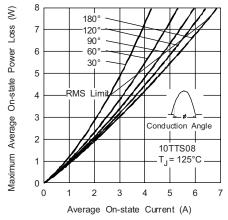


Fig. 3 - On-State Power Loss Characteristics

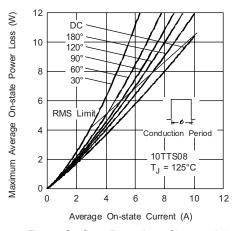


Fig. 4 - On-State Power Loss Characteristics

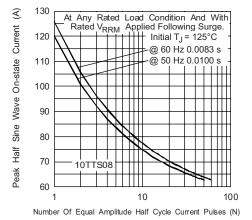


Fig. 5 - Maximum Non-Repetitive Surge Current

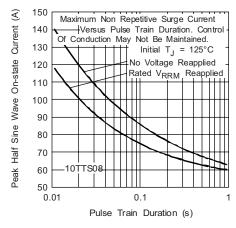


Fig. 6 - Maximum Non-Repetitive Surge Current



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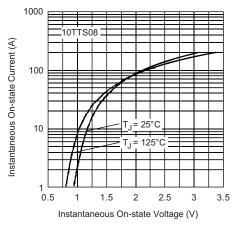


Fig. 7 - On-State Voltage Drop Characteristics

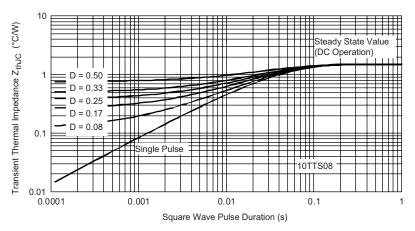


Fig. 8 - Thermal Impedance  $Z_{\text{thJC}}$  Characteristics

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#### **ORDERING INFORMATION TABLE**

Device code	10	Т	Т	S	08	S	TRL	PbF
	1	2	3	4	5	6	7	8

1 - Current rating, RMS value

2 - Circuit configuration:

T = Single thyristor

3 - Package:

T = TO-220AC

4 - Type of silicon:

S = Converter grade

5 - Voltage code x 100 = V<sub>RRM</sub>

- S = TO-220 D<sup>2</sup>PAK (SMD-220) version

7 - Tape and reel option:

• TRL = Left reel

• TRR = Right orientation reel

8 - • None = Standard production

• PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?95046				
Part marking information	www.vishay.com/doc?95054			
Packaging information	www.vishay.com/doc?95032			

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